



## Description

This BOSA is a high performance optical sub-assembly in single fiber by using 1310nm transmitter and 1490nm receiver.

The transmitter section uses a multiple quantum well 1310nm FP laser supporting burst-mode operation. The receiver section uses a TO-can built in a long wavelength PIN diode and a 1.25Gbps transimpedance amplifier.

## Applications

- EPON BOB ONU optical modem
- EPON ONU transceiver
- FTTH Bi-directional play

## EPON ONU BOSA BA-21 series T1.25G/R1.25G

### Features

- Single fiber receptacle type bi-directional transmission design for digital communication
- Symmetric 1.25Gbps downstream and 1.25Gbps upstream data link transmission
- Laser welded transmitter and epoxy cured receiver package
- Integrated micro-optics WDM filters for dual wavelength Tx/Rx operation at 1310/1490nm
- 1310nm InGaAsP/InP MQW FP laser diode transmission with high bandwidth InGaAs monitor photodiode
- 1490nm digital PIN photodiode integrated with 1.25Gbps, 3.3V continuous mode transimpedance-amplifier
- High optical isolation from external source and low optical cross-talk from internal source
- -5°C to +75°C commercial operating temperature range with excellent temperature dependent optical power tracking error

### Standard

- Compliant with IEEE802.3ah™-2004 1000BASE-PX10/20 communication protocol
- The Compliant with Telcordia GR-468 reliability test criterion
- Compliant with Telcordia GR-326 connector qualification standard
- Compliant with RoHS6 standard

## 1. Absolute Maximum Ratings

Item	Unit	Min	Max	Note
Forward Current for LD	mA	--	150	
Reverse Voltage for LD	V	--	2	
Forward Current for MPD	mA	--	2	
Reverse Voltage for MPD	V	--	20	
Optical Power for Rx	dBm	5	--	
TIA Supply Voltage	V	-0.4	4.0	
Operating Temp	°C	-5	75	
Storage Temperature	°C	-40	85	
Storage Relative Humidity	%	85	--	
Solder Reflow Temperature	°C	--	260	(*1)
Hand Soldering Temperature	°C	500		

(\*1): For soldering by iron and 10 seconds on leads

## 2. Transmitter Electro-Optical Characteristics (T<sub>c</sub>=25°C, CW)

Item	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Threshold Current	I <sub>th</sub>	T <sub>c</sub> =25°C	1	--	15	mA
		T <sub>c</sub> =-5~75°C	1	--	35	mA
Optical Output Power (*2)	P <sub>f</sub>	I <sub>f</sub> =I <sub>th</sub> +20mA, T <sub>c</sub> =25 °C	1.2	--	3.0	mW
		I <sub>f</sub> =I <sub>th</sub> +20mA, T <sub>c</sub> =-5~75°C	0.80	--	--	mW
Slope Efficiency	η	I <sub>f</sub> =I <sub>th</sub> +20mA, T <sub>c</sub> =25 °C	0.06	--	0.15	mW/mA
		I <sub>f</sub> =I <sub>th</sub> +20mA, T <sub>c</sub> =-5~75°C	0.04	--	--	mW/mA
Forward Current	I <sub>f</sub>	P <sub>f</sub> =1.3mW, T <sub>c</sub> =-5~75°C	--	--	65	mA
Operating Voltage	V <sub>op</sub>	I <sub>f</sub> =I <sub>th</sub> +20mA	--	1.2	1.5	V
Peak Wavelength	λ	I <sub>f</sub> =I <sub>th</sub> +20mA	1290	1310	1330	nm
	λ	I <sub>f</sub> =I <sub>th</sub> +20mA, T <sub>c</sub> =-5~75°C	1260	1310	1360	nm
Spectrum Width (RMS)	Δλ	I <sub>f</sub> =I <sub>th</sub> +20mA	--	2.0	2.5	nm
Rise/Fall time	τ <sub>r</sub> /τ <sub>f</sub>	20%~80%, I <sub>b</sub> =I <sub>th</sub>	--	100	200	ps
Monitor Current	I <sub>m</sub>	P <sub>f</sub> =1.3mW	100	--	1000	μA

Monitor Capacitance	C	V <sub>rp</sub> =5V, f=1MHz	4	-	15	pF
Monitor Dark Current	I <sub>d</sub>	V <sub>rp</sub> =5V	-	-	100	nA
Tracking Error (*3)	TE	CW, T <sub>c</sub> = -5~ 75°C,	-1.3	-	1.3	dB

(\*2): Launched into 9/125μm SMF

(\*3):  $\Delta Pf = 10 \times \log (Pf (Tc) / Pf (25^\circ C))$ , I<sub>m</sub> hold (@Pf=1.3mW, 25°C)

### 3. Receiver Electro-Optical Characteristics (T<sub>c</sub>=25°C, V<sub>cc</sub>=3.3V)

Item	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Supply Voltage	V <sub>cc</sub>		3.0	3.3	3.6	V
Supply Current	I <sub>cc</sub>	No loads	-	28	35	mA
Operating Wavelength	λ		1480	-	1500	nm
Sensitivity	Sen	λ=1490nm, 1.25Gbps, PRBS7, NRZ, ER=10dB, BER=10E-12	-	-	-28.5	dBm
Overload	OL		-1.0	-	-	dBm
Output Impedance	R <sub>out</sub>	Single end	40	50	60	Ω
Differential Output Voltage	V <sub>pp</sub>	100Ω differential load, 1.25Gbps	-	-	1000	mV
Optical Return Loss	ORL1310	1310nm	-	-	-12	dB
	ORL1490	1490nm	-	-	-20	dB
Rise/Fall time	τ <sub>r</sub> /τ <sub>f</sub>	20%~80%	200	300	400	ps
Optical Crosstalk	X-talk	1310nm internal TX/1490nm RX	-	-	-45	dB
Optical Isolation	ISO1	from external light source, λ=1260~1360nm	25	-	-	dB
	ISO2	from external light source, λ=1550~1560nm	35	-	-	dB

## 4. Dimension Outline

